

500 Watts - 60 Volts, 300 μs, 10% L-Band Radar 1200 - 1400 MHz

#### **GENERAL DESCRIPTION**

The 1214GN-500 is an internally matched, COMMON SOURCE, class AB, GaN on SiC HEMT transistor capable of providing over 18dB gain, 500 Watts of pulsed RF output power at 300µs pulse width, 10% duty factor across the 1200 to 1400 MHz band.

Market Application – 1214GN-500 is designed for L-Band Pulsed Radar

#### **ABSOLUTE MAXIMUM RATINGS**

**Maximum Power Dissipation** 

Device Dissipation @ 25°C 1000 W

**Maximum Voltage and Current** 

Drain-Source Voltage ( $V_{DSS}$ ) 150 V Gate-Source Voltage ( $V_{GS}$ ) -8 to +0 V

**Maximum Temperatures** 

Storage Temperature (T<sub>STG</sub>) -55 to +125° C Operating Junction Temperature +250 °C 55-KR
Common Source



#### **ELECTRICAL CHARACTERISTICS @ 25°C**

Symbol	Characteristics	Test Conditions		Тур	Max	Units
Pout	Output Power	Pout=500W, Freq=1200,1300,1400 MHz	500	550		W
Gp	Power Gain	Pout=500W, Freq=1200,1300,1400 MHz	17	18.5		dB
ηd	Drain Efficiency	Pout=500W, Freq=1200,1300,1400 MHz	48	55		%
Dr	Droop	Pout=500W, Freq=1200,1300,1400 MHz			1.0	dB
VSWR-T	Load Mismatch	Pout=500W, Freq= 1300MHz			3:1	
	Tolerance					
Өјс	Thermal Resistance	Pulse Width=300uS, Duty=10%			0.16	°C/W

• Bias Condition: Vdd=+60V, Idq=100mA average current (Vgs= -2.0 ~ -4.5V typical)

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#### **FUNCTIONAL CHARACTERISTICS @ 25°C**

I <sub>D(Off)</sub>	Drain leakage current	$V_{gS} = -8V, V_D = 65V$		10	mA
$I_{G(Off)}$	Gate leakage current	$V_{gS} = -8V, V_D = 0V$		8	mA
BV <sub>DSS</sub>	Drain-source breakdown voltage	V <sub>gs</sub> =-8V, I <sub>D</sub> = 10mA	250		V

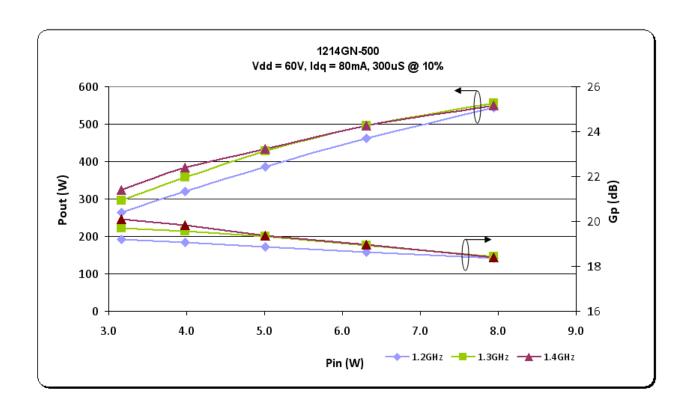
Export Classification: EAR-99



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#### TYPICAL BROAD BAND PERFORMACE DATA

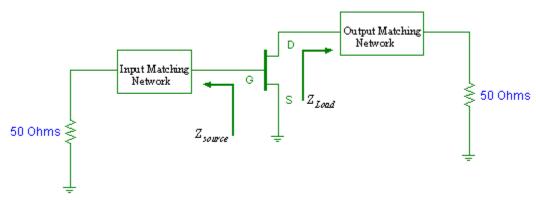
Frequency	Pin (W)	Pout (W)	ld (A)	RL (dB)	Nd (%)	G (dB)	Droop (dB)
1200 MHz	8	544	1.86	-16	52	18.36	0.6
1300 MHz	8	556	1.76	-13	55	18.45	0.5
1400 MHz	8	550	1.58	-13	61	18.4	0.4





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#### TRANSISTOR IMPEDANCE INFORMATION



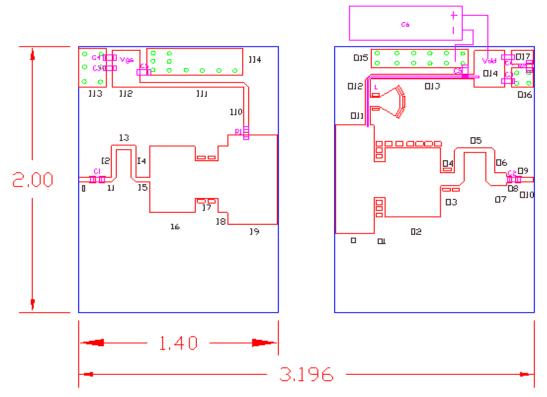
Note:  $Z_{source}$  is looking into the input circuit;  $Z_{Load}$  is looking into the output circuit.

Impedance Data					
Freq (GHz)	Zs	ZI			
1.2	1.17 – j 1.16	2.08 – j 2.14			
1.3	1.20 – j .91	2.07 – j 1.67			
1.4	1.26 – j .15	2.04 – j 1.18			



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### **TEST CIRCUIT DIAGRAM**



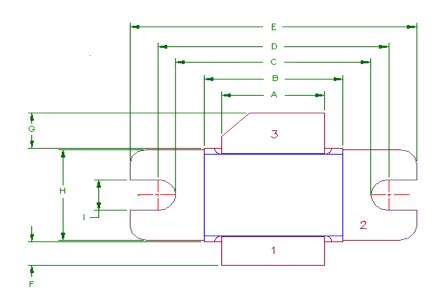
Board Material: Roger Duriod 6006 @ 25 Mil Thickness, Er=6.15

	Component List				hysical Circ	uit Layout	Г	<b>Output P</b>	hysical Cir	cuit Layout
ltem	Description		Value	Item	W (mil)	L (mil)		ltem	W (mil)	L (mil)
C1	Chip Cap A size	ATC800A1010JT250XT	100pF	I	35	116		0	820	270
C2	Chip Cap A size	ATC800A680JT250XT	68pF	11	35	84		01	270	80
C3	Chip Cap B size	ATC200B103KW50XT	10,000pF	12	35	230		02	520	390
C4	Chip Cap B size	ATC100B102102KW50XT	1000pF	13	35	100		03	95	95
C5	Chip Cap B size	ATC100B101FW1000XT	100pF	14	35	230		04	70	160
C6	Electrolytic Cap (63√)	ANY	4700uF	15	35	100		05	35	150
R1	Chip Resistor size 0805	ANY	20.5 ohms	16	500	315		06	70	160
R2	Chip Resistor size 0805	ANY	2 ohm	17	280	160		07	95	80
L	RF Choke 20 AWG Copper wire			18	500	70		08	47	40
	L=1350 mil solder on top of the	output choke		19	670	350		09	47	40
				110	35	355		010	35	85
Note:				l11	35	745		011	35	180
	Need 2x of C3,C4,C5			112	275	200		012	35	180
				l13	280	190		013	35	730
				114	200	670		014	270	200
								015	138	680
								016	150	150
								017	98	150

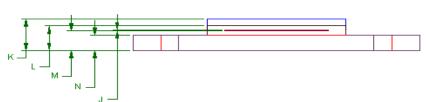


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#### 55-KR PACKAGE DIMENSION







1	=	Gate
2	=	Source
3	=	Drain

Dimension	Min (mil)	Min (mm)	Max (mil)	Max (mm)
Α	370	9.40	372	9.44
В	498	12.65	500	12.7
С	700	17.78	702	17.83
D	830	21.08	832	21.13
E	1030	26.16	1032	26.21
F	101	2.56	102	2.59
G	151	3.84	152	3.86
Н	385	9.78	387	9.83
I	130	3.30	132	3.35
J	003	.076	004	0.10
K	135	3.43	137	3.48
L	105	2.67	107	2.72
M	085	2.16	86	2.18
N	065	1.65	66	1.68

For the most current data, consult MICROSEMI's website: <a href="www.MICROSEMI.com">www.MICROSEMI.com</a>
Specifications are subject to change, consult the RFIS factory at <a href="(408) 986-8031">(408) 986-8031</a> for the latest information



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#### Revision History

Revision Level / Date	Para. Affected	Description
0.1 / 18 January 2013	-	Initial Preliminary Release

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